



DMP2108UCB6

Product Summary

| BV _{DSS} | R _{D1D2(ON)} TYP ID1D2 T _A = +25° | | | | | |
|-------------------|--|-------|--|--|--|--|
| -20V | $82m\Omega @ V_{GS} = -4.5V$ | -3.0A | | | | |

Description

This new generation MOSFET has been designed to minimize the onstate resistance ($R_{D1D2(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Battery Management
- Load Switch
- Battery Protection

DUAL P-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

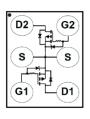
- Low Qg & Qgd
 - Dual PMOS in Common-Source Configuration
- Small Footprint 1.5mm × 1.0mm
- Gate ESD Protection to 6kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: U-WLB1510-6
- Terminal Connections: See Diagram Below
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal: Finish SnAgCu. Solderable per MIL-STD-202 Method 208 (e1)
- UBM Opening: 280µm

U-WLB1510-6 (Type B)





Top View

Ordering Information (Note 4)

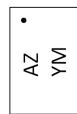
| b | | | |
|--------|---|---|----------------------------|
| | Part Number | Case | Packaging |
| | DMP2108UCB6-7 | U-WLB1510-6 (Type B) | 3000/Tape & Reel |
| Notes: | 1. No purposely added lead. Fully EU Direct | tive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/ | 863/EU (RoHS 3) compliant. |

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



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AZ= Product Type Marking Code YM = Date Code Marking Y = Year (ex: G = 2019) M = Month (ex: N = November)

| Date Code Key | | | | | | | | | | |
|---------------|-------|--------|-------|---------|------|------|-----|------|-----|------|
| Year | 2019 | 2020 | 202 | 1 2 | 2022 | 2023 | | 2024 | ; | 2025 |
| Code | G | Н | | | J | К | | L | | Μ |
| | | | | | | | | | | |
| Month | Jan F | eb Mar | Apr N | lav Jun | Jul | Aua | Sep | Oct | Nov | Dec |

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Code

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|---|-----------------|--|-------------------|---------------|------|
| Drain-Source Voltage | | | V _{DS} | -20 | V |
| Gate-Source Voltage | | | V _{GS} | -6 | V |
| Continuous Drain Current (Note 5) V_{GS} = -4.5V | Steady State | T _A = +25°C T _A = +70°C | I _{D1D2} | -2.25 -1.8 | А |
| Continuous Drain Current (Note 6) $V_{GS} = -4.5V$ Steady State $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | | | I _{D1D2} | -3.0 -2.4 | А |
| Continuous Source Pin Current (Note 6) | | | I _S | -2.0 | А |
| Continuous Gate Clamp Current (Note 6) | | | lg | -0.5 | А |
| Pulsed Source Pin Current (Pulse Duration 10µs, Duty Cycle ≤ 1%) | | | I _{SM} | -39 | А |
| Pulsed Gate Clamp Current (Pulse Duration 10µs, Duty Cycle ≤ 1%) | | | I _{GM} | -7 | А |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|------------------|-------------|------|
| Total Power Dissipation (Note 5) | PD | 0.84 | W |
| Total Power Dissipation (Note 6) | PD | 1.2 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{0JA} | 152.7 | °C/W |
| Thermal Resistance, Junction to Ambient (Note 6) | R _{0JA} | 105.4 | °C/W |
| Operating and Storage Temperature Range | TJ, TSTG | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|---|-----------------------|------|-------|------|------|--|--|
| OFF CHARACTERISTICS (Note 7) | | | | | • | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -20 | _ | _ | V | $V_{GS} = 0V, I_{DS} = -250 \mu A$ | |
| Zero Gate Voltage Drain Current $@T_C = +25^{\circ}C$ | I _{DSS} | | — | -1 | μA | $V_{DS} = -16V, V_{GS} = 0V$ | |
| Gate-Source Leakage | IGSS | | — | -100 | nA | $V_{GS} = -6V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | • | | |
| Gate Threshold Voltage | V _{GS(TH)} | -0.5 | -0.75 | -1.1 | V | $V_{DS} = V_{GS}, I_{DS} = -250 \mu A$ | |
| | | | 82 | 100 | | V _{GS} = -4.5V, I _{D1D2} = -1A | |
| | R _{D1D2(ON)} | | 110 | 150 | mΩ | $V_{GS} = -2.5V, I_{D1D2} = -1A$ | |
| Statia Drain Source On Desistance | | _ | 160 | 240 | | V _{GS} = -1.8V, I _{D1D2} = -1A | |
| Static Drain-Source On-Resistance | | _ | 42 | 55 | | V _{GS} = -4.5V, I _{DS} = -1A | |
| | R _{DS(ON)} | _ | 56 | 80 | mΩ | V _{GS} = -2.5V, I _{DS} = -1A | |
| | | _ | 80 | 120 | | V _{GS} = -1.8V, I _{DS} = -1A | |
| DIODE CHARACTERISTICS | 1 1 | | | | | | |
| Diode Forward Voltage (Note 6) | V _{SD} | | -0.72 | -1 | V | $V_{GS} = 0V, I_{DS} = -1A$ | |
| Reverse Recovery Charge | Q _{RR} | — | 2.3 | — | nC | $V_{DD} = -10V, I_F = -1A,$ | |
| Reverse Recovery Time | t _{RR} | | 7.1 | | ns | di/dt = 200A/µs | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | • | | |
| Input Capacitance | Ciss | _ | 269 | _ | pF | | |
| Output Capacitance | Coss | | 142 | _ | pF | $V_{DS} = -10V, V_{GS} = 0V,$ = f = 1.0MHz | |
| Reverse Transfer Capacitance | C _{rss} | | 7.6 | | pF | | |
| Total Gate Charge (-4.5V) | Qg | | 2.1 | _ | nC | | |
| Gate-Source Charge | Q _{gs} | | 0.3 | | nC | V _{GS} = -4.5V, V _{DS} = -10V, | |
| Gate-Drain Charge | Q _{gd} | — | 0.3 | | nC | I _{DS} = -1A | |
| Gate Charge at V _{TH} | Q _{g(TH)} | _ | 0.16 | _ | nC | 1 | |
| Turn-On Delay Time | t _{D(ON)} | | 6 | _ | ns | | |
| Turn-On Rise Time | t _R | _ | 7 | _ | ns | V _{DD} = -10V, V _{GS} = -4.5V | |
| Turn-Off Delay Time | t _{D(OFF)} | | 34 | | ns | I_{DS} = -1A, R_G = 30 Ω | |
| Turn-Off Fall Time | tF | _ | 16 | _ | ns | | |

6. Device mounted on FR-4 material with 1 inch² (6.45cm²), 2 oz. (0.071mm thick) Cu.

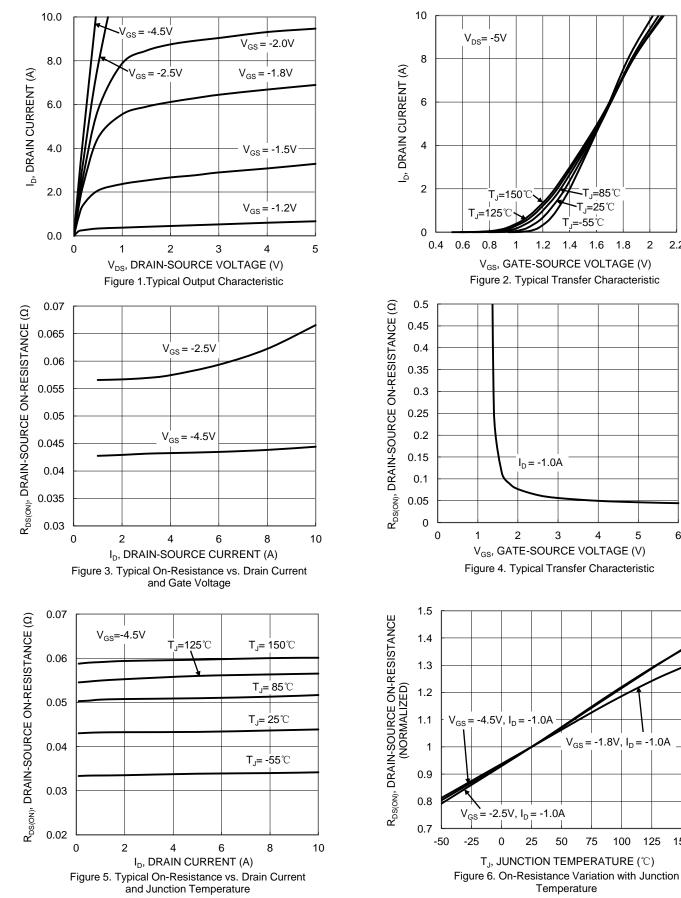
7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to production testing.



2.2

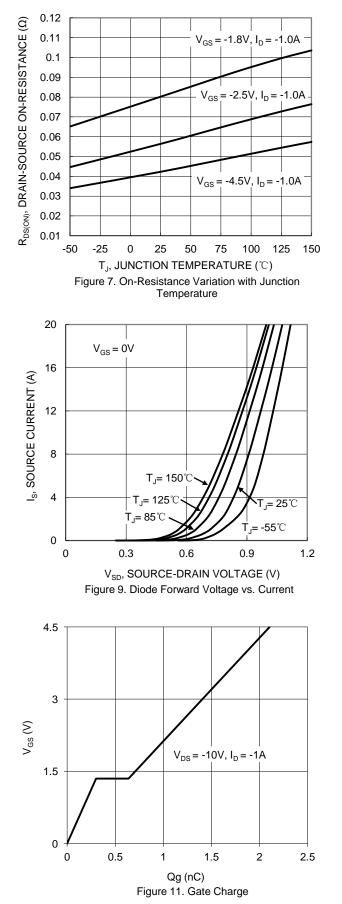
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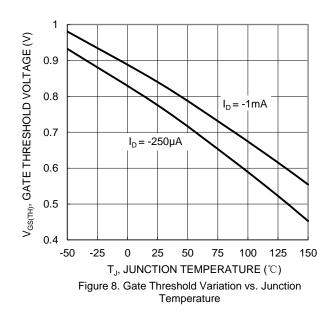


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DMP2108UCB6





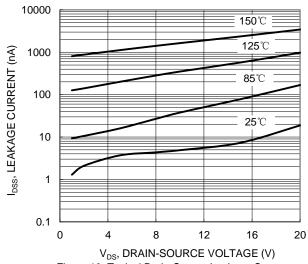
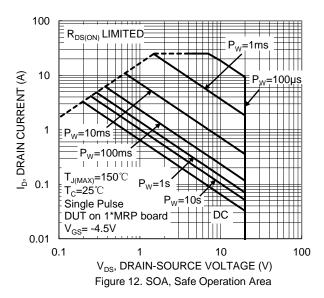
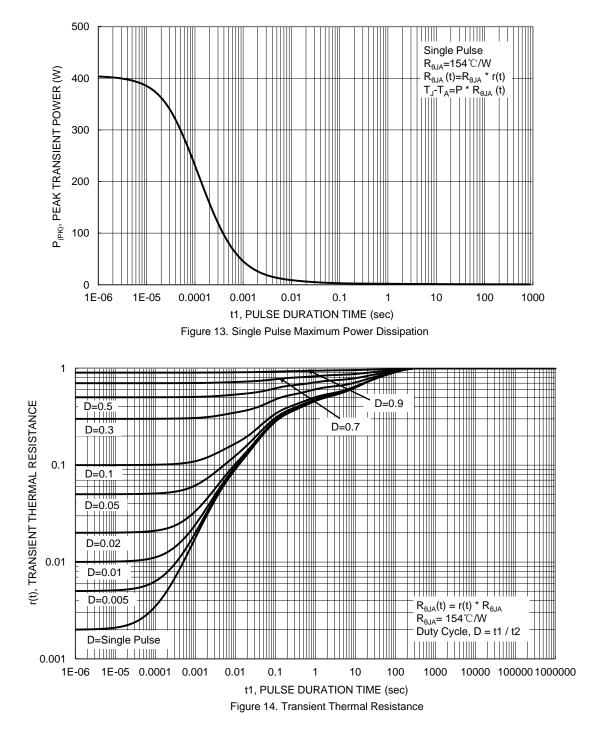


Figure 10. Typical Drain-Source Leakage Current vs. Voltage



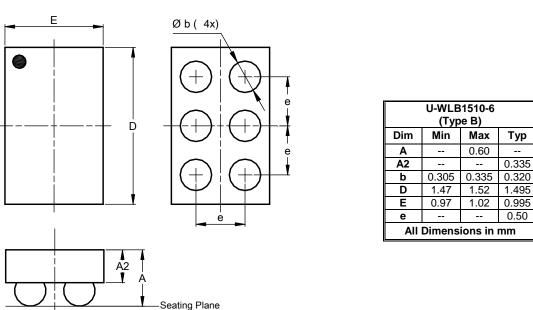






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

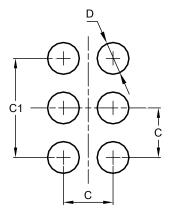


U-WLB1510-6 (Type B)

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-WLB1510-6 (Type B)



| Dimensions | Value |
|------------|---------|
| | (in mm) |
| С | 0.50 |
| C1 | 1.00 |
| D | 0.30 |

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